imall

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Discrete POWER & Signal **Technologies**



PN3638 PN3638A



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
VCBO	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4.9	V
lc	Collector Current - Continuous	800	mA
TJ, Tstg	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

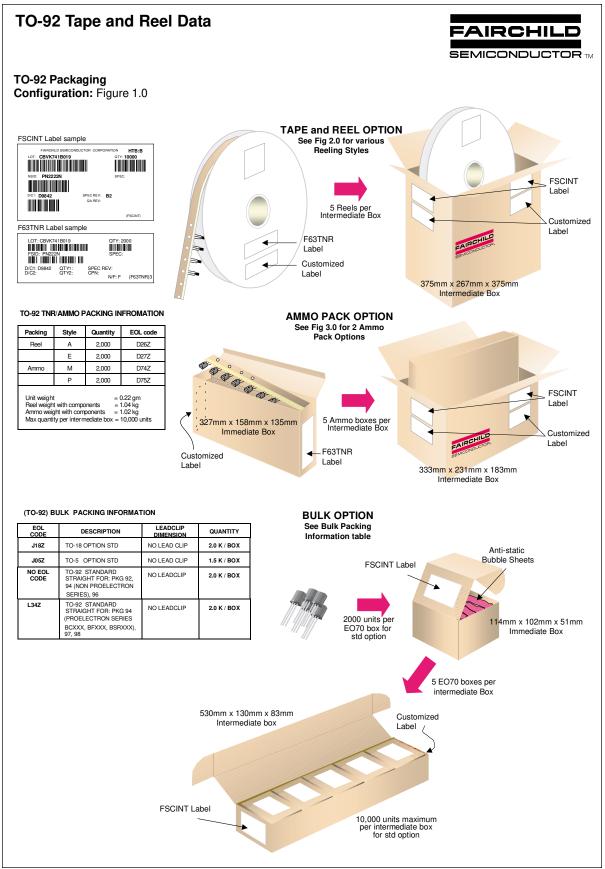
Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		PN3638/A	
PD	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
R _{0JC}	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta_{JA}}$	Thermal Resistance, Junction to Ambient	200	°C/W

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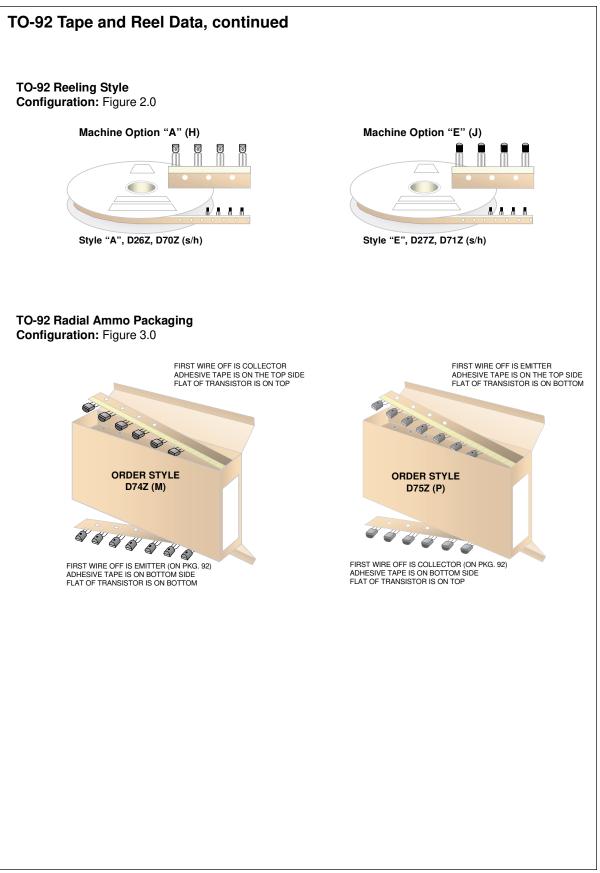
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Electrical Characteristics TA = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions	Min	Max	Units		
OFF CHA	RACTERISTICS						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	25		V		
V _{(BR)CES}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 100 \ \mu A, \ I_{\rm B} = 0$	25		V		
V(BR)CBO	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	25		V		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \ \mu A, \ I_C = 0$	4.0		V		
ICES	Collector-Cutoff Current			35 2.0	nA μA		
ON CHAF	RACTERISTICS*						
h _{FE}	DC Current Gain	V _{CE} = 1.0 V, I _C = 50 mA					
		PN3638	30				
		PN3638A V _{CE} = 2.0 V, I _C = 300 mA	100				
		PN3638	30				
		PN3638A	20				
		V _{CE} = 10 V, I _C = 100 mA PN3638 PN3638A	20 80				
		V _{CE} = 10 V, I _C = 1.0 mA PN3638A	100				
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 2.5 \text{ mA}$		0.25	V V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 2.5 \text{ mA}$		1.0 1.1	V		
· DE (Sat)		$I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$	0.8	2.0	V		
SMALL S	IGNAL CHARACTERISTICS						
Cob	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$		20	~		
		PN3638 PN3638A		20 10	pF pF		
Cib	Input Capacitance	V _{BE} = 0.5 V, f = 1.0 MHz			191		
		PN3638		65 25	pF pF		
h _{fe}	Small-Signal Current Gain	PN3638A Ic = 50 mA, V _{CE} = 3.0 V,		20	рг		
91 Y		f = 100 MHz PN3638	1.0				
		PN3638A	1.5				
		I _C = 10 mA, V _{CE} = 10 V, f = 1.0 kHz PN3638	25				
		PN3638A	100				
1 _{ie}	Input Impedance	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V},$		2.0	kΩ		
h _{oe}	Output Admittance	f = 1.0 kHz		1.2	μmhos		
h _{re}	Voltage Feedback Ratio	PN3638 PN3638A		26 15	x10 ⁻⁴ x10 ⁻⁴		
SWITCHI	NG CHARACTERISTICS						
lon	Turn-on Time	V _{CC} = 10 V, I _C = 300 mA,	75		ns		
d.	Delay Time	$I_{B1} = 30 \text{ mA}$	20		ns		
a ir	Rise Time		70		ns		
off	Turn-off Time	Vcc = 10 V, lc = 300 mA	170		ns		
.oπ .s	Storage Time	$I_{B1} = I_{B2} = 30 \text{ mA}$	140		ns		
~	Fall Time	-	70	ł	ns		

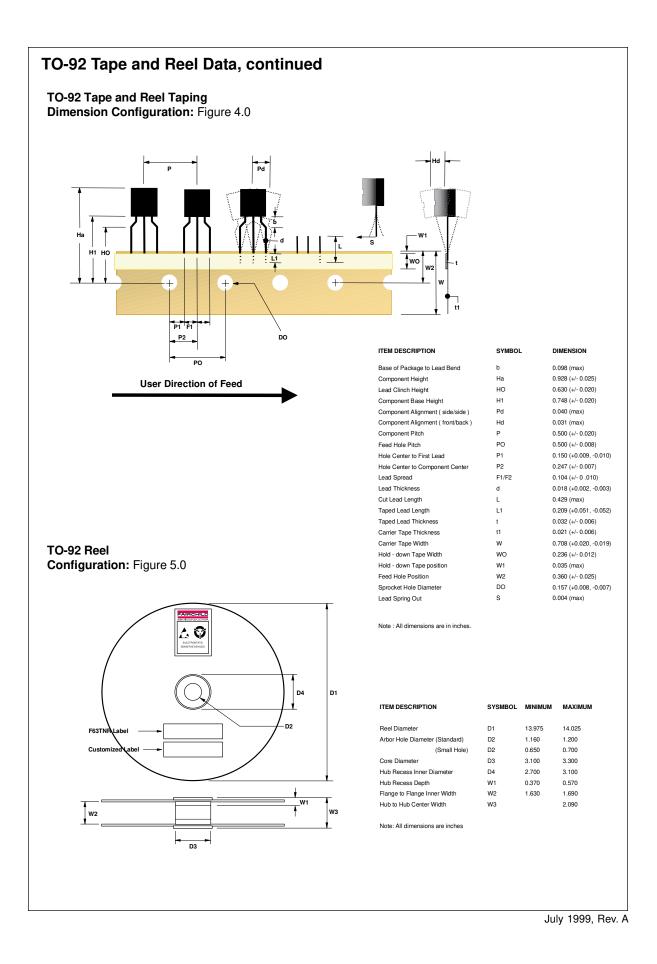
PN3638 / PN3638A

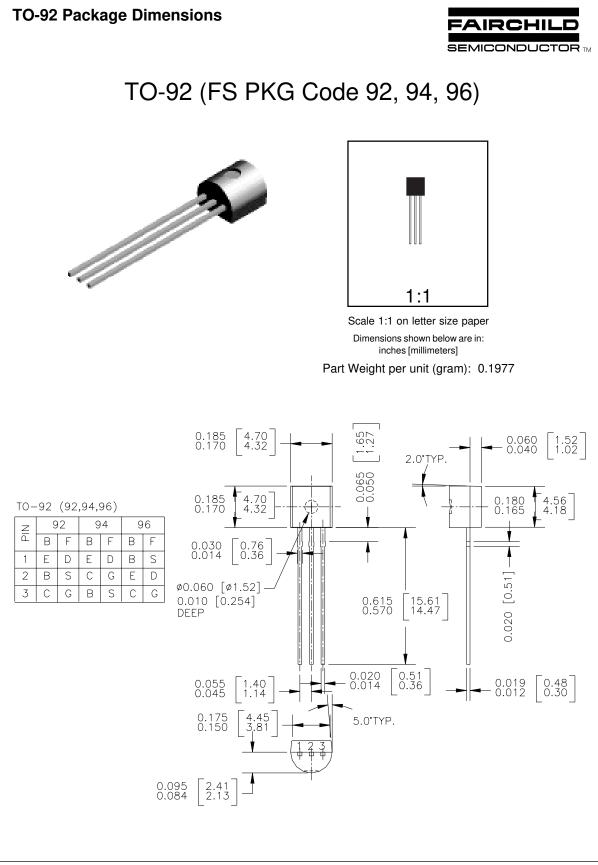


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